N. ჰ. რ.	სამეცნიერო შრომების დასახელება	ნაბეჭდი ან ხელნაწერი	გამომცემლობა, ჟურნალი (ნომერი, წელი) ან საავტორო მოწმობის ნომერი	ნაბეჭდი თაბახის ან გვერდების რაოდენობა	თანაავტორის გვარი
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